Preferred Device

Self-protected FET with Temperature and Current Limit

HDPlus devices are an advanced series of power MOSFETs which utilize ON Semiconductor's latest MOSFET technology process to achieve the lowest possible on–resistance per silicon area while incorporating smart features. Integrated thermal and current limits work together to provide short circuit protection. The devices feature an integrated Drain–to–Gate Clamp that enables them to withstand high energy in the avalanche mode. The Clamp also provides additional safety margin against unexpected voltage transients. Electrostatic Discharge (ESD) protection is provided by an integrated Gate–to–Source Clamp.

Features

- Current Limitation
- Thermal Shutdown with Automatic Restart
- Short Circuit Protection
- Low R_{DS(on)}
- I_{DSS} Specified at Elevated Temperature
- Avalanche Energy Specified
- Slew Rate Control for Low Noise Switching
- Overvoltage Clamped Protection
- Pb-Free Packages are Available

MOSFET MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage Internally Clamped	V _{DSS}	40	Vdc
Drain-to-Gate Voltage Internally Clamped (R _{GS} = 1.0 M Ω)	V_{DGR}	40	Vdc
Gate-to-Source Voltage	V _{GS}	±16	Vdc
	I _D I _{DM}	Internally Limited	
Total Power Dissipation @ $T_A = 25$ °C (Note 1) @ $T_A = 25$ °C (Note 2) @ $T_A = 25$ °C (Note 3)	P _D	1.1 1.73 8.93	W
Thermal Resistance, Junction–to–Tab Junction–to–Ambient (Note 1) Junction–to–Ambient (Note 2)	$\begin{array}{c} R_{\thetaJT} \\ R_{\thetaJA} \\ R_{\thetaJA} \end{array}$	14 114 72.3	°C/W
Single Pulse Drain-to-Source Avalanche Energy (V_{DD} = 25 Vdc, V_{GS} = 5.0 Vdc, V_{DS} = 40 Vdc, I_{L} = 2.8 Apk, L = 80 mH, R_{G} = 25 Ω)	E _{AS}	300	mJ
Operating and Storage Temperature Range	T _J , T _{stg}	-55 to 150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. Mounted onto min pad board.
- 2. Mounted onto 1" pad board.
- 3. Mounted onto large heatsink.

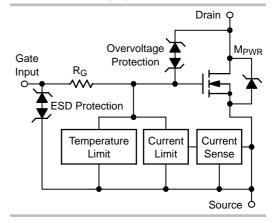


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6.0 AMPERES* 40 VOLTS CLAMPED

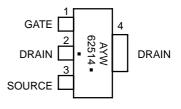
 $R_{DS(on)} = 90 \text{ m}\Omega$





SOT-223 CASE 318E STYLE 3

MARKING DIAGRAM



A = Assembly Location

Y = Year W = Work Week

62514 = Specific Device Code Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

^{*}Limited by the current limit circuit.

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$\textbf{MOSFET ELECTRICAL CHARACTERISTICS} \ (T_J = 25^{\circ}\text{C unless otherwise noted})$

Characteristic			Min	Тур	Max	Unit
OFF CHARACTERISTICS				1	I.	
Drain-to-Source Clamped Breakdown Voltage (V _{GS} = 0 Vdc, I _D = 250 μAdc) (V _{GS} = 0 Vdc, I _D = 250 μAdc, T _J = 150°C)			42 42	46 45	50 50	Vdc
Zero Gate Voltage Drain Current (V _{DS} = 32 Vdc, V _{GS} = 0 Vdc) (V _{DS} = 32 Vdc, V _{GS} = 0 Vdc, T _J = 150°C)			1 1	0.5 2.0	2.0 10	μAdc
Gate Input Current $(V_{GS} = 5.0 \text{ Vdc}, V_{DS} = 0 \text{ Vdc})$ $(V_{GS} = -5.0 \text{ Vdc}, V_{DS} = 0 \text{ Vdc})$			<u>-</u> -	50 550	100 1000	μAdc
ON CHARACTERISTICS						
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = 150 \ \mu Adc)$ Threshold Temperature Coefficient (Negative)			1.0	1.7 4.0	2.0 6.0	Vdc mV/°C
Static Drain-to-Source On-Resistance (Note 4) (V_{GS} = 10 Vdc, I_D = 1.4 Adc, T_J @ 25°C) (V_{GS} = 10 Vdc, I_D = 1.4 Adc, T_J @ 150°C)				90 165	100 190	mΩ
Static Drain-to-Source On-Resistance (Note 4)				105 185	120 210	mΩ
Source-Drain Forward On Voltage (I _S = 7 A, V _{GS} = 0 V)			-	1.05	-	V
SWITCHING CHARACTERISTICS						
Turn-on Delay Time	$R_{L} = 4.7 \ \Omega, \ V_{in} = 0 \ to \ 10\% \ V_{DD} = 12 \ V_{in} = 10 \$	t _{d(on)}	-	4.0	8.0	μs
Turn-on Rise Time	$R_{L} = 4.7 \ \Omega, \ V_{in} = 0 \ to \ 10 \ V, \ V_{DD} = 12 \ V$	t _{rise}	-	11	20	μS
Turn-off Delay Time	90% V_{in} to 90% I_{D} R_{L} = 4.7 Ω , V_{in} = 10 to 0 V, V_{DD} = 12 V	t _{d(off)}	-	32	50	μs
Turn-off Fall Time	90% I_D to 10% I_D $R_L = 4.7 \ \Omega$, $V_{in} = 10$ to 0 V, $V_{DD} = 12$ V	t _{fall}	-	27	50	μs
Slew-Rate On	$R_L = 4.7 \Omega,$ $V_{in} = 0 \text{ to } 10 \text{ V}, V_{DD} = 12 \text{ V}$	-dV _{DS} /dt _{on}	-	1.5	2.5	μs
Slew-Rate Off	Slew–Rate Off $R_{L} = 4.7 \ \Omega,$ $V_{in} = 10 \text{ to } 0 \text{ V}, V_{DD} = 12 \text{ V}$		-	0.6	1.0	μS
SELF PROTECTION CHARACTERISTIC	S (T _J = 25°C unless otherwise noted)					
Current Limit	$(V_{GS} = 5.0 \text{ Vdc})$ $(V_{GS} = 5.0 \text{ Vdc}, T_J = 150^{\circ}\text{C})$	I _{LIM}	6.0 3.0	9.0 5.0	11 8.0	Adc
Current Limit	(V _{GS} = 10 Vdc) (V _{GS} = 10 Vdc, T _J = 150°C)	I _{LIM}	7.0 4.0	10.5 7.5	13 10	Adc
Temperature Limit (Turn-off)	V _{GS} = 5.0 Vdc	T _{LIM(off)}	150	175	200	°C
Temperature Limit (Circuit Reset)	V _{GS} = 5.0 Vdc	T _{LIM(on)}	135	160	185	°C
Temperature Limit (Turn-off)	V _{GS} = 10 Vdc	T _{LIM(off)}	150	155	185	°C
Temperature Limit (Circuit Reset)	V _{GS} = 10 Vdc	T _{LIM(on)}	130	140	170	°C
ESD ELECTRICAL CHARACTERISTICS	6 (T _J = 25°C unless otherwise noted)					
Electro-Static Discharge Capability	e Capability Human Body Model (HBM)		4000	-	_	V
Electro-Static Discharge Capability	Machine Model (MM)	ESD	400	-	-	V

^{4.} Pulse Test: Pulse Width = 300 μs, Duty Cycle = 2%.

TYPICAL ELECTRICAL CHARACTERISTICS

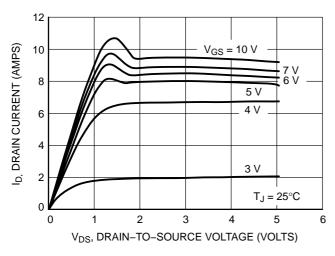


Figure 1. Output Characteristics

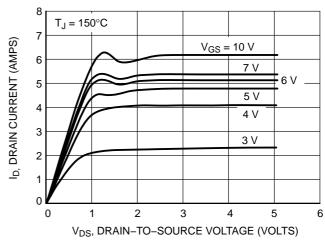


Figure 2. Output Characteristics

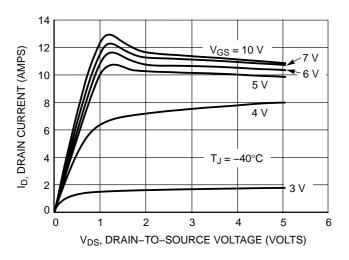


Figure 3. Output Characteristics

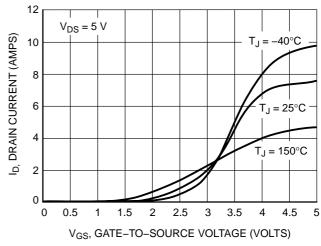


Figure 4. Transfer Characteristics

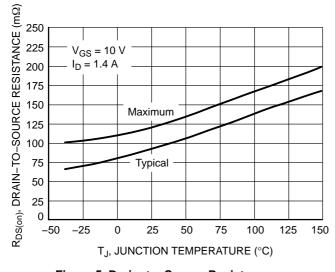


Figure 5. Drain-to-Source Resistance versus Junction Temperature

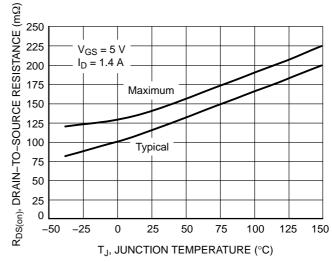


Figure 6. Drain-to-Source Resistance versus Junction Temperature

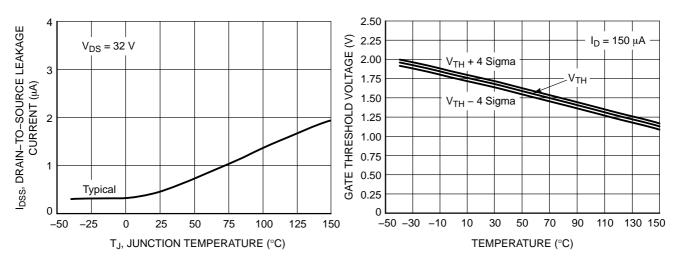


Figure 7. Drain-to-Source Resistance versus Junction Temperature

Figure 8. Gate Threshold Voltage versus Temperature

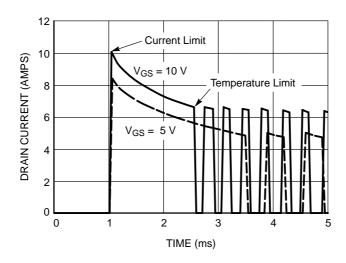


Figure 9. Short-circuit Response

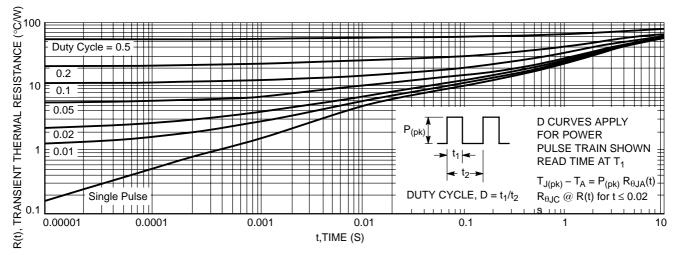


Figure 10. Transient Thermal Resistance (Non-normalized Junction-to-Ambient mounted on minimum pad area)

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ORDERING INFORMATION

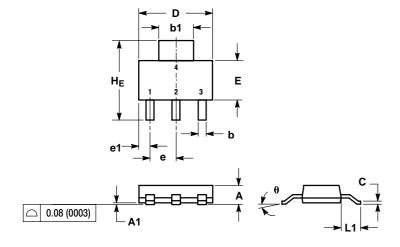
Device	Package	Shipping [†]	
NIF62514T1	SOT-223		
NIF62514T1G	SOT-223 (Pb-Free)	1000 / Tape & Reel	
NIF62514T3G	SOT-223 (Pb-Free)	4000 / Tape & Reel	

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

NIF62514

PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 **ISSUE L**



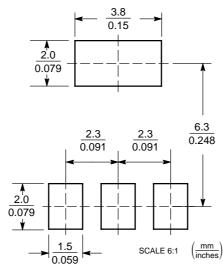
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
С	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	-	10°

STYLE 3:

- PIN 1. GATE
 - 2. DRAIN 3. SOURC 4. DRAIN
 - SOURCE DRAIN

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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